Chiral magic-angle twisted bilayer graphene in a magnetic field: Landau level correspondence, exact wave functions, and fractional Chern insulators

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We show that the flat bands in the chiral model of magic-angle twisted bilayer graphene remain exactly flat in the presence of a perpendicular magnetic field. This is shown by an exact mapping between the model and the lowest Landau level wave functions at an effective magnetic field, in which the external field is either augmented or reduced by one flux quantum per unit cell. When the external field reaches one flux quantum per unit cell, the model exhibits a topological phase transition. These findings allow us to analyze a Jain series of fractional Chern insulators states in the exactly flat band, and to point out an unconventional dependence of the energy gap on the magnetic field.

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Magic-angle twisted bilayer graphene (MATBG) [1–5] has generated interest as a platform that combines two major components of modern condensed matter physics: strong interactions and topology. The first is a result of the flat bands occurring at charge neutrality [1,2]. As for the second, the flat bands host "fragile" topology [6-9], and can be decomposed into two Chern bands of opposite Chern numbers (per spin and valley) [10,11], which are connected by parity-time ($C_2 T$) symmetry. As a result of this combination the phase diagram of MATBG was shown to host a wide range of phenomena including superconductivity [3] (possibly unconventional [3,12]), correlated insulators [4], correlated Chern insulators [13–16], and most recently fractional Chern insulators [17]. Another point of interest in TBG (and in moiré materials in general) is that, as a result of the large lattice size, it is experimentally possible to apply a magnetic field of the order of a single flux quantum per unit cell [15,18-20]. This allows the experimental study phenomena such as the Hofstadter spectrum [21], and even fractional states emerging on the Hofstadter subbands [22,23].

In the study of MATBG, a significant role was played by the so-called chiral model [24]. In this model one artificially turns off the tunneling terms between atoms of the same sublattice in the two graphene sheets (*AA*, *BB*). The resulting Hamiltonian has an additional chiral symmetry (acting as σ_z in sublattice space). One then finds a series of "magic" twist angles [24,25] at which there are eight exactly flat bands (two per spin and graphene valley index) at zero energy, which could be chosen to have a definite Chern number $C = \pm 1$ and sublattice polarization. The Chern/sublattice polarization, therefore, serves as a good quantum number for the flat bands (a review of the model symmetries with and without the chiral approximation is given in [10,26]). In this work we use the chiral model at the magic angle to study the interplay between topology, exactly flat bands, and an external perpendicular magnetic field b in twisted bilayer graphene. For the rest of the text we focus on a single valley and ignore the spin. We make here several observations.

(1) The application of a perpendicular field does not make the bands disperse but rather leaves them exactly flat. The magnetic field does not change the Chern number of each band or its association with a particular sublattice. This was first shown by [27]. Here it is shown by a different method.

(2) The main effect of the magnetic field is to change the number of states within each band. While at zero field the number of states per unit cell is n = 1, this number changes to $n(b) = 1 \pm C\Phi/\Phi_0$, where Φ is the flux per unit cell and Φ_0 is the flux quantum. This change contradicts the intuitive expectation that a Bloch band should have one state per unit cell, i.e., $n(b) \equiv 1$. It is, however, necessitated by the bands being Chern bands, just as the degeneracy of a Landau level must be linear in the magnetic field. If one imagines filling one such band, and adiabatically turning on a magnetic field b(t)confined to within a large circle in the sample, the azimuthal electric field generated by the time variation of b generates a Hall current into the circle. The in-flowing electrons must have states to occupy, and thus the number of states in the band must vary. Equivalently, this may be seen as an example for the Streda formula, applied separately to each band [28]:

$$\sigma_{xy} = -\left(\frac{\partial n}{\partial b}\right)_{\mu},\tag{1}$$

where *n* is the electron density. We absorb the charge *e* into the definition of the fields (b = eB) and assume throughout the work that $\hbar = c = 1$. The formula is valid as long as the chemical potential μ is in the gap and the Chern number remains a good quantum number.

(3) As long as $|\Phi| < \Phi_0$ and all bands are full, the total Chern number of the zero-energy bands is zero. As $\Phi = \Phi_0$ the C = -1 band is emptied, and the Hall conductivity

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FIG. 1. (a) Hofstadter diagram (generated using the method of [18,33]) for the cMATBG model. The bands remain exactly flat for any applied external magnetic field. For $\Phi = \Phi_0$, the gap closes and the total Chern number of the flat bands changes from 0 to 2. (b) Number of states per moiré unit cell as a function of magnetic flux. After the phase transition, the number grows as it would for two decoupled Landau levels.

changes to a nonzero integer. Thus, at $\Phi = \Phi_0$, the gap must close to allow for this change. Due to the chiral symmetry, the gap closes from both sides of the E = 0 line (see Fig. 1), and we obtain a single Dirac cone in the $\Phi = \Phi_0$ band structure.

(4) We derive exact wave functions for the exactly flat Chern bands with the applied magnetic field. They are given in general in the form

$$\psi(\mathbf{r}) = f(z)e^{-\frac{\rho_{\rm eff}}{4}|z|^2}G(\mathbf{r}),$$
(2)

where z = x + iy and f(z) is analytic. The *b*-independent functions $G(\mathbf{r})$ are spinors in the layer indices [29]. They are invariant under translations up to a position-dependent phase and inherit the C_3 symmetry of the original model. The effective magnetic field b_{eff} is

$$b_{\rm eff} = b + C \frac{2\pi}{A_M},\tag{3}$$

where C is the Chern number of the layer and A_M is the moiré unit cell area. The restricted effect of b on the wave

function may be indicated by a direct substitution of (2) in the Schrödinger equation that corresponds to the Hamiltonian (4). This formulation makes explicit the relation between the chiral model wave functions and the lowest Landau level (LLL), in which $G(\mathbf{r}) \equiv 1$, and generalizes the results of [24,30] to a general magnetic field. The form given in (2) describes the wave functions in the C = +1 bands. Different bands are then obtained by C_2 and $C_2 \mathcal{T}$ symmetries.

Following [24], we write the chiral MATBG (cMATBG) Hamiltonian in the presence of a magnetic field as

$$\mathcal{H}_{chiral} = \begin{pmatrix} 0 & \mathcal{D}_{-b}^*(-\mathbf{r}) \\ \mathcal{D}_b(\mathbf{r}) & 0 \end{pmatrix},$$

$$\mathcal{D}_b(\mathbf{r}) = \begin{pmatrix} -2ik_{\theta}^{-1}(\bar{\partial} + zb/4) & \alpha U(\mathbf{r}) \\ \alpha U(-\mathbf{r}) & -2ik_{\theta}^{-1}(\bar{\partial} + zb/4) \end{pmatrix}, \quad (4)$$

where $\bar{\partial} = \frac{1}{2}(\partial_x + i\partial_y)$ and $U(\mathbf{r})$ is a position dependent tunneling potential [31]. The Hamiltonian acts on the bispinor $(\psi(\mathbf{r}), \chi(\mathbf{r}))$ where each spinor lives on a different graphene sublattice (A/B) and the "spins" are the layer indices. We use the symmetric gauge $A = \frac{b}{2}(y\hat{\mathbf{x}} - x\hat{\mathbf{y}})$ (so that b > 0 implies a magnetic field in the $-\hat{\mathbf{z}}$ direction for negatively charged carriers), and assume the commensurability condition $b = \frac{p}{q}\frac{2\pi}{AM}$, where p, q are coprime integers. This assumption allows us to label the wave functions by common eigenvalues (lattice momenta) of \tilde{T}_1^q , \tilde{T}_2 , where \tilde{T}_i are the magnetic translation operators by

$$a_{1} = \frac{4\pi}{3k_{\theta}}(0, -1),$$

$$a_{2} = \frac{4\pi}{3k_{\theta}}\left(\frac{\sqrt{3}}{2}, \frac{1}{2}\right).$$
(5)

We provide an explicit form of \tilde{T}_i in the Supplemental Material (SM) [32]. In this form of \mathcal{H}_{chiral} the translations act as nonsymmorphic symmetries where a phase difference $\bar{U} = (1, e^{2\pi i/3})$ must be added between the layers. This phase can be removed by gauge choice and will not be considered further.

In the absence of a magnetic field, the authors of [24] found that for specific values of α , the "magic angles" of the system, the model has two exactly flat bands at zero energy. The bands can be labeled by the sublattice index and have a definite Chern number C = 1 for the A sublattice and C = -1 for the B sublattice. The flatness is sensitive to model parameters, and either changing α away the magic value or adding any AA tunneling will result in a finite bandwidth. One would then expect that any addition of a magnetic field b will also destroy the exact flatness of the bands. As we now show, this is not the case.

Landau level correspondence and exact wave functions. Let us consider the relationship between the zero-energy wave functions and the wave functions of the lowest Landau level (LLL), which are the ground states of the Landau level Hamiltonian

$$H_{\rm LL} = (-i\nabla + A)^2. \tag{6}$$

We recall that in the symmetric gauge the LLL wave functions are given by Eq. (2) with $G(\mathbf{r}) = 1$ and $b_{\text{eff}} = b$. For cMATBG in the absence of an external magnetic field, one can write an exact correspondence between any wave function in the perfectly flat Chern band and a function in the LLL at $b = \frac{2\pi}{A_M}$: As was shown by [24], at the magic angle the wave function $\psi_K(\mathbf{r})$, corresponding to the *A*-sublattice polarized wave function at the *K* point, has a zero at $\mathbf{r}_0 = (2\mathbf{a}_1 + \mathbf{a}_2)/3$. Since the kinetic term of $\mathcal{D}_0(\mathbf{r})$ is proportional to the identity matrix we can use $\psi_K(\mathbf{r})$ to construct zero modes of $\mathcal{D}_0(\mathbf{r})$ of the form [24,34]

$$\psi(\mathbf{r}) = \tilde{f}(z) \frac{\psi_K(\mathbf{r})}{\vartheta_1\left(\frac{z-z_0}{a_1}\big|\omega\right)},\tag{7}$$

where $\omega = e^{2\pi i/3}$, $z_0 = r_{0,x} + ir_{0,y}$ (we use nonbold symbols for the complex versions of the vectors $a_i = \mathbf{a}_{i,x} + i\mathbf{a}_{i,y}$), and $\vartheta_1(z \mid \tau)$ is the Jacobi theta function. The definition of $\vartheta_1(z \mid \tau)$ is provided in the SM [32]. Here we note that

$$\vartheta_1(z \mid \tau) = 0 \leftrightarrow z = m + n\tau \tag{8}$$

for integer *m*, *n*. In this way the zeros of the theta function cancel the zeros of $\psi_K(\mathbf{r})$, making the wave functions (7) normalizable. Furthermore, the function $\vartheta_1(z \mid \tau)$ is periodic in Re(*z*), with a period of one. When Im(*z*) is taken to infinity, the function oscillates, with an envelope that diverges as $e^{\frac{\pi(lmz)^2}{\tau}}$. This envelope makes (7) decay as a Gaussian in the *y* direction. Writing $\tilde{f} = f e^{\frac{\pi}{2A_M}(z-2z_0)^2}$ we can write the wave function as a product of an analytic function f(z) multiplied by a function that decays like a Gaussian in all directions, similar to the wave function of the lowest Landau level in the symmetric gauge [35]. With this, we find that there is a correspondence between LLL wave functions and wave functions of the cMATBG flat bands, given by

$$f(z)e^{-\frac{2\pi}{A_M}\frac{1}{4}|z|^2} \mapsto f(z)\frac{e^{\frac{\pi}{2A_M}(z-2z_0)^2}\psi_K(\mathbf{r})}{\vartheta_1\left(\frac{z-z_0}{a_1}\middle|\omega\right)}.$$
(9)

The critical property of (9) is that if f(z) is chosen such that the wave function on the left-hand side (LHS) is an eigenfunction of the magnetic translations, the wave functions on the right-hand side (RHS) will be eigenfunctions of the translation operators in cMATBG. It therefore maps a set of orthogonal eigenfunctions to a set of orthogonal eigenfunctions and thus provides a basis of wave functions for the cMATBG flat bands.

For $b \neq 0$ one sees that the for any $\psi(\mathbf{r})$ of the form (7) the function $e^{-\frac{b}{4}|z|^2}\psi(\mathbf{r})$ solves $\mathcal{D}_b\psi(\mathbf{r}) = 0$. The more difficult part of our argument is to obtain the number of orthogonal functions of this form. To do so we extend the correspondence (9) by using the effective magnetic field b_{eff} defined in (3), and mapping

$$f(z)e^{-\frac{b_{\text{eff}}}{4}|z|^{2}} \mapsto f(z)\frac{e^{\frac{1}{4}(-b|z|^{2}+\frac{2\pi}{A_{M}}(z-2z_{0})^{2})}\psi_{K}(\mathbf{r})}{\vartheta_{1}(\frac{z-z_{0}}{a_{1}}|\omega)}.$$
 (10)

The fact that the RHS gives a zero-mode of \mathcal{H}_{chiral} can be shown by direct substitution. In contrast with (9), the transformation (10) is not guaranteed to preserve orthogonality between the wave functions: we see that in the former case both sides can be labels by eigenvalues of the translation/magnetic translation operators by (a_1, a_2) . In the latter case, on the other hand, the LLL wave functions can be classified by the magnetic translation symmetries $(\frac{q}{p+q}a_1, a_2)$ while the cMATBG model has only the magnetic translation symmetries $(q a_1, a_2)$. This means that the correspondence gives p + q wave functions for each k in the magnetic moiré Brillouin zone of TBG, whose orthogonality is not constrained by symmetries. Nevertheless, the resulting p + q wave functions remain linearly independent. Otherwise, we could construct a finite linear combination of them that will be mapped to zero under (10), which is clearly impossible for any nonzero f. This shows that the Landau level correspondence gives us p + q states per k in the cMATBG magnetic moiré Brillouin zone, or equivalently $1 + \frac{\Phi}{\Phi_0}$ per unit cell. We can identify G(r) as presented in (2) as

$$G(\mathbf{r}) = \frac{e^{\frac{\pi}{2A_M} \left(|z|^2 + (z - 2z_0)^2\right)} \psi_K(\mathbf{r})}{\vartheta_1 \left(\frac{z - z_0}{a_1} \mid \omega\right)}.$$
 (11)

We can also explicitly write the Bloch wave functions obtained from the above correspondence as

$$\psi_{k,n}(\mathbf{r}) = \vartheta_1 \left(\frac{q+p}{q} \frac{z-z_0}{a_1} + \frac{k}{b_2} + \frac{n\omega}{q} + \frac{ia_1a_2b}{8\pi} \left| \frac{q+p}{q} \omega \right) \times e^{(k_y + 2\pi i \frac{n-p/2}{qa_1})z} \frac{e^{-\frac{k}{4}(|z|^2 + z^2)}\psi_K(\mathbf{r})}{\vartheta_1(\frac{z-z_0}{a_1}|\omega)},$$
(12)

where n = 1, ..., p + q and $b_2 = k_{\theta}(\sqrt{3}, 0)$ is a reciprocal lattice vector. The functions $\psi_{k,n}$ for different *n* are not orthogonal but form a linearly independent set. They can be made orthogonal by a Gram-Schmidt process.

We note that the above analysis works for negative and positive *b* alike, and that the result for *B* sublattice can be obtained by applying the $C_2\mathcal{T}$ symmetry together with $b \rightarrow -b$. The number of *B*-polarized states will then be $1 - \frac{\Phi}{\Phi_0}$. For both cases, this agrees with the arguments given above.

For $\Phi > \Phi_0$ we find that there are additional p - q *A*-polarized zero modes so that the total number of zero modes is $2\frac{\Phi}{\Phi_0}$ per unit cell (as we would have for two uncoupled Landau levels). These additional functions cannot, however, be obtained from (10) and we need to seek a more general form of zero-energy wave functions for (4). This form is discussed in the SM [32]. By the Streda formula (1) we can conclude that the total Chern number of the zero-energy wave functions becomes C = 2 for $\Phi > \Phi_0$. The transition of the Chern number should be accompanied by a closure of the gap, which results in two additional zero modes at the Γ point $k_0 = (0, -k_0)$. In the SM we show how one can write explicit forms for the additional zero modes [32].

Notice also that off the magic angle we have exactly $2\frac{\Phi}{\Phi_0}$ zero-energy wave functions, which are all *A*-sublattice polarized, and are given by

$$\psi_{z.m.}(\mathbf{r}) = \nu(\mathbf{r})\psi_{K/K'}(\mathbf{r}), \qquad (13)$$

where $v(\mathbf{r})$ is a function in the LLL [Eq. (2) with magnetic field *b* and $G(\mathbf{r}) = 1$] and $\psi_{K/K'}(\mathbf{r})$ are the zero-energy *A*-polarized wave functions at zero magnetic field, at the *K* and *K'* points of the moiré Brillouin zone.

Relation to the Atiyah-Singer index theorem. An elegant way to reproduce the number of zero energy wave functions is by means the Atiyah-Singer index theorem [36,37]. As was pointed out in [38], the Hamiltonian (4) is a Hamiltonian of a Dirac electron in a $U(1) \times SU(2)$ gauge potential, where the tunneling term couples to the SU(2) sector and the external field couples to the U(1) sector. The non-Abelian gauge potential \mathcal{A} is given by

$$\mathcal{A} = AI + A_{\text{n.a.}}^{i} \sigma_{i},$$

$$A_{\text{n.a.}}^{i} = \frac{1}{2} \{ \text{Re}[\text{Tr}(\sigma_{i}\mathcal{U})], \text{Im}[\text{Tr}(\sigma_{i}\mathcal{U})] \},$$

$$\mathcal{U} = i\alpha k_{\theta} \begin{pmatrix} 0 & U(\mathbf{r}) \\ U(-\mathbf{r}) & 0 \end{pmatrix}, \qquad (14)$$

where *I* is the identity matrix and summation over the three Pauli matrices is implied in the first line. At zero energy, eigenstates reside purely on one sublattice, and we can discuss the number $n_{A/B}$ of zero-energy states on the two sublattices (per unit cell). Assuming periodic boundary condition, the difference $n_A - n_B$ between the number of zero-energy modes (per unit cell) in the *A* and *B* sublattices is a form of a Chiral anomaly. This difference can be obtained exactly by means of the Atiyah-Singer index theorem [39]:

$$n_A - n_B = \frac{1}{2\pi N_s} \int \mathrm{Tr} \mathcal{F}_{xy} d\boldsymbol{r}, \qquad (15)$$

where N_s is the number of unit cells and \mathcal{F}_{xy} is the curvature associated with \mathcal{A} , given by

$$\mathcal{F}_{xy} = \partial_x \mathcal{A}_y - \partial_y \mathcal{A}_x + \frac{1}{2} [\mathcal{A}_x, \mathcal{A}_y].$$
(16)

The non-Abelian part has no contribution to the trace [40], while the integral of the Abelian part gives

$$n_A - n_B = 2\frac{\Phi}{\Phi_0}.\tag{17}$$

This result does not depend on the system being at the magic angle or on the magnetic field being uniform in space. The total number $n_A + n_B$ of zero-energy eigenstates may vary considerably, being $2 \max(\frac{\Phi}{\Phi_0}, 1)$ at the magic angle and $2\frac{\Phi}{\Phi_0}$ off the magic angle, but the difference $n_A - n_B$ (in the chiral model) is governed by the topology.

Fractional Chern insulators. Since the zero energy bands of the model can be presented as Chern bands, one may expect that at partial filling and in the presence of electron-electron interactions the ground state would be a fractional Chern insulator (FCI) in which both time-reversal and flavor symmetries are spontaneously broken [23,41,42]. A recent experiment [17] has shown that indeed an FCI state can be found at fillings $3 < n_e < 4$ (n_e refers to the number of electrons per unit cell added, counted from charge neutrality), with nonzero magnetic field. These states seem to be connected to zero-field FCI states [43–45] but require an external magnetic field to be stabilized. The analysis of [17] suggests that the importance of the external magnetic field is that it flattens the Berry curvature, thus making the FCI more favorable [30,46].

Our expressions for the wave functions of the flat bands in the presence of a perpendicular magnetic field naturally suggest a few observations regarding the FCI states. Starting with the case of one partially filled Chern band, and defining *n* as the number of electrons per unit cell in that band, the filling fraction of the band is $n/(1 + C_p \frac{\Phi}{\Phi_0})$, with C_p its Chern number. An FCI of the Jain series [47] would form when $n = (1 + C_p \frac{\Phi}{\Phi_0}) \frac{j}{2mj+1}$ with *m*, *j* integers. When the partially filled band coexists with N_b full bands of Chern numbers C_i (with $i = 1, ..., N_b$), the relation between the total number of electrons per unit cell n_e and the flux density $\frac{\Phi}{\Phi_0}$ is

$$n_e = \sum_{i=1}^{N_b} \left(1 + C_i \frac{\Phi}{\Phi_0} \right) + \left(1 + C_p \frac{\Phi}{\Phi_0} \right) \frac{j}{2mj+1}, \quad (18)$$

as expected from the Streda formula (1), for constant m, j the number of electrons varies when the flux is changed, and the slope of the variation is the corresponding Hall conductivity of the incompressible state.

For p = 1, for example, we get a series analogous to the Laughlin series, where the analog to the Laughlin wave function (in the chiral limit) is

$$\Psi(\{z_i\}) = \prod_{i < j} (z_i - z_j)^m \prod_i e^{-\frac{b_{\text{eff}}}{4}|z_i|^2} G(\mathbf{r}_i), \qquad (19)$$

generalizing the results of [34] to an arbitrary magnetic field.

When the FCI forms in a band whose Chern number is negative, C = -1, the effective magnetic field *decreases* in magnitude when the external magnetic field is increased. This decrease has an interesting implication on the characteristic interaction energy scale of the FCI (with Coulomb interactions), which is

$$V = \frac{e^2}{\varepsilon \ell_{B,\text{eff}}},\tag{20}$$

where $\ell_{B,\text{eff}}^{-2} = b_{\text{eff}}$, and ε is the dielectric constant. We expect the energy gap of the FCI to be determined by V, up to a proportionality factor that depends on the band-structure geometry [42,46], but has only weak magnetic field dependence. For large b, then Eq. (20) suggests that the FCI energy gap may decrease with an increasing magnetic field, in contrast to that of fractional quantum Hall states. In that limit we expect the FCI state to be destabilized.

Discussion. As we focused in this letter on the chiral model Hamiltonian, it is worthwhile to discuss which of our conclusions extend beyond it. In the case where a spontaneous symmetry breaking results in a band with a definite Chern number (as is expected, e.g., in $3 < \nu < 4$ in TBG), one can still use the effective magnetic field approach to discuss fractional states in this regime. Furthermore, an interesting future direction is to use our results as a starting point for analyzing the stability of FCI states as a function of the magnetic field in the Chiral model and beyond. Finally, the correspondence (9) [and therefore (10)] relies on nothing more but the existence of a kinetic term acting as an antiholomorphic derivative with no dependence on the spinor direction, together with the zero of $\psi_K(\mathbf{r})$. It would be interesting to ask whether one can find additional models exhibiting the same correspondence.

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- E. Suárez Morell, J. D. Correa, P. Vargas, M. Pacheco, and Z. Barticevic, Flat bands in slightly twisted bilayer graphene: Tight-binding calculations, Phys. Rev. B 82, 121407(R) (2010).
- [2] R. Bistritzer and A. H. MacDonald, Moiré bands in twisted double-layer graphene, Proc. Natl. Acad. Sci. U.S.A. 108, 12233 (2011).
- [3] Y. Cao, V. Fatemi, S. Fang, K. Watanabe, T. Taniguchi, E. Kaxiras, and P. Jarillo-Herrero, Unconventional superconductivity in magic-angle graphene superlattices, Nature (London) 556, 43 (2018).
- [4] Y. Cao, V. Fatemi, A. Demir, S. Fang, S. L. Tomarken, J. Y. Luo, J. D. Sanchez-Yamagishi, K. Watanabe, T. Taniguchi, E. Kaxiras, R. C. Ashoori, and P. Jarillo-Herrero, Correlated insulator behaviour at half-filling in magic-angle graphene superlattices, Nature (London) 556, 80 (2018).
- [5] E. Y. Andrei and A. H. MacDonald, Graphene bilayers with a twist, Nat. Mater. 19, 1265 (2020).
- [6] H. C. Po, L. Zou, A. Vishwanath, and T. Senthil, Origin of Mott Insulating Behavior and Superconductivity in Twisted Bilayer Graphene, Phys. Rev. X 8, 031089 (2018).
- [7] H. C. Po, H. Watanabe, and A. Vishwanath, Fragile Topology and Wannier Obstructions, Phys. Rev. Lett. 121, 126402 (2018).
- [8] Z. Song, Z. Wang, W. Shi, G. Li, C. Fang, and B. A. Bernevig, All Magic Angles in Twisted Bilayer Graphene are Topological, Phys. Rev. Lett. **123**, 036401 (2019).
- [9] J. Ahn, S. Park, and B.-J. Yang, Failure of Nielsen-Ninomiya Theorem and Fragile Topology in Two-Dimensional Systems with Space-Time Inversion Symmetry: Application to Twisted Bilayer Graphene at Magic Angle, Phys. Rev. X 9, 021013 (2019).
- [10] N. Bultinck, E. Khalaf, S. Liu, S. Chatterjee, A. Vishwanath, and M. P. Zaletel, Ground State and Hidden Symmetry of Magic-Angle Graphene at even Integer Filling, Phys. Rev. X 10, 031034 (2020).
- [11] F. Xie, A. Cowsik, Z.-D. Song, B. Lian, B. A. Bernevig, and N. Regnault, Twisted bilayer graphene. VI. An exact diagonalization study at nonzero integer filling, Phys. Rev. B 103, 205416 (2021).
- [12] Y. Cao, J. M. Park, K. Watanabe, T. Taniguchi, and P. Jarillo-Herrero, Pauli-limit violation and re-entrant superconductivity in moiré graphene, Nature 595, 526 (2021).
- [13] K. P. Nuckolls, M. Oh, D. Wong, B. Lian, K. Watanabe, T. Taniguchi, B. A. Bernevig, and A. Yazdani, Strongly correlated Chern insulators in magic-angle twisted bilayer graphene, Nature (London) 588, 610 (2020).
- [14] G. Chen, A. L. Sharpe, E. J. Fox, Y. H. Zhang, S. Wang, L. Jiang, B. Lyu, H. Li, K. Watanabe, T. Taniguchi, Z. Shi, T. Senthil, D. Goldhaber-Gordon, Y. Zhang, and F. Wang, Tunable correlated Chern insulator and ferromagnetism in a moiré superlattice, Nature (London) 579, 56 (2020).
- [15] Y. Saito, J. Ge, L. Rademaker, K. Watanabe, T. Taniguchi, D. A. Abanin, and A. F. Young, Hofstadter subband ferromagnetism and symmetry-broken Chern insulators in twisted bilayer graphene, Nat. Phys. 17, 478 (2021).
- [16] A. T. Pierce, Y. Xie, J. M. Park, E. Khalaf, S. H. Lee, Y. Cao, D. E. Parker, P. R. Forrester, S. Chen, K. Watanabe, T. Taniguchi, A. Vishwanath, P. Jarillo-Herrero, and A. Yacoby, Unconventional sequence of correlated Chern insulators in magic-angle twisted bilayer graphene, arXiv:2101.04123.

- [17] Y. Xie, A. T. Pierce, J. M. Park, D. E. Parker, E. Khalaf, P. Ledwith, Y. Cao, S. H. Lee, S. Chen, P. R. Forrester, K. Watanabe, T. Taniguchi, A. Vishwanath, P. Jarillo-Herrero, and A. Yacoby, Fractional Chern insulators in magic-angle twisted bilayer graphene, arXiv:2107.10854.
- [18] R. Bistritzer and A. H. MacDonald, Moiré butterflies in twisted bilayer graphene, Phys. Rev. B 84, 035440 (2011).
- [19] C. R. Dean, L. Wang, P. Maher, C. Forsythe, F. Ghahari, Y. Gao, J. Katoch, M. Ishigami, P. Moon, M. Koshino, T. Taniguchi, K. Watanabe, K. L. Shepard, J. Hone, and P. Kim, Hofstadter's butterfly and the fractal quantum Hall effect in moiré superlattices, Nature (London) **497**, 598 (2013).
- [20] J. Herzog-Arbeitman, Z.-D. Song, N. Regnault, and B. A. Bernevig, Hofstadter Topology: Noncrystalline Topological Materials at High Flux, Phys. Rev. Lett. 125, 236804 (2020).
- [21] D. R. Hofstadter, Energy levels and wave functions of Bloch electrons in rational and irrational magnetic fields, Phys. Rev. B 14, 2239 (1976).
- [22] L. Wang, Y. Gao, B. Wen, Z. Han, T. Taniguchi, K. Watanabe, M. Koshino, J. Hone, and C. R. Dean, Evidence for a fractional fractal quantum Hall effect in graphene superlattices, Science 350, 1231 (2015).
- [23] E. M. Spanton, A. A. Zibrov, H. Zhou, T. Taniguchi, K. Watanabe, M. P. Zaletel, and A. F. Young, Observation of fractional Chern insulators in a van der Waals heterostructure, Science 360, 62 (2018).
- [24] G. Tarnopolsky, A. J. Kruchkov, and A. Vishwanath, Origin of Magic Angles in Twisted Bilayer Graphene, Phys. Rev. Lett. 122, 106405 (2019).
- [25] Y. Ren, Q. Gao, A.H. MacDonald, and Q. Niu, WKB Estimate of Bilayer Graphene's Magic Twist Angles, Phys. Rev. Lett. 126, 016404 (2021).
- [26] P. J. Ledwith, E. Khalaf, and A. Vishwanath, Strong coupling theory of magic-angle graphene: A pedagogical introduction, arXiv:2105.08858.
- [27] F. K. Popov and A. Milekhin, Hidden wave function of twisted bilayer graphene: The flat band as a landau level, Phys. Rev. B 103, 155150 (2021).
- [28] P. Streda, Theory of quantised Hall conductivity in two dimensions, J. Phys. C: Solid State Phys. 15, L717 (1982).
- [29] J. Wang, Y. Zheng, A. J. Millis, and J. Cano, Chiral approximation to twisted bilayer graphene: Exact intravalley inversion symmetry, nodal structure, and implications for higher magic angles, Phys. Rev. Res. 3, 023155 (2021).
- [30] J. Wang, J. Cano, A. J. Millis, Z. Liu, and B. Yang, Exact landau level description of geometry and interaction in a flatband, arXiv:2105.07491.
- [31] See Supplemental Material at http://link.aps.org/supplemental/ 10.1103/PhysRevB.104.L121405 for a derivation of \mathcal{H}_{chiral} , which includes Ref. [24].
- [32] See Supplemental Material at http://link.aps.org/supplemental/ 10.1103/PhysRevB.104.L121405 for a discussion of the symmetries of the cMATBG, properties of the theta function, and additional wavefunction at $\Phi \ge \Phi_0$.
- [33] Y.-H. Zhang, H. C. Po, and T. Senthil, Landau level degeneracy in twisted bilayer graphene: Role of symmetry breaking, Phys. Rev. B 100, 125104 (2019).
- [34] P. J. Ledwith, G. Tarnopolsky, E. Khalaf, and A. Vishwanath, Fractional Chern insulator states in twisted bilayer graphene: An analytical approach, Phys. Rev. Res. 2, 023237 (2020).

- [35] The factor of 2 before z_0 assures that the decay is like $e^{\frac{\pi}{2A_M}|z|^2}$ and not $e^{\frac{\pi}{2A_M}|z-z_0|^2}$.
- [36] M. F. Atiyah and I. M. Singer, Dirac operators coupled to vector potentials, Proc. Natl. Acad. Sci. U.S.A. 81, 2597 (1984).
- [37] M. Nakahara, *Geometry, Topology and Physics*, 2nd ed. (CRC, Boca Raton, FL, 2003).
- [38] P. San-Jose, J. González, and F. Guinea, Non-Abelian Gauge Potentials in Graphene Bilayers, Phys. Rev. Lett. 108, 216802 (2012).
- [39] We follow the form for twisted spin bundles, provided in Eq. (12.86) of [37].
- [40] The vanishing contribution of the SU(2) part is related to the fact that $\Pi_2[SU(2)] = 0$.
- [41] B. A. Bernevig and T. L. Hughes, *Topological Insulators and Topological Superconductors*, edited by T. L. Hughes (Princeton University Press, Princeton, NJ, 2013).

- [42] S. A. Parameswaran, R. Roy, and S. L. Sondhi, Fractional Chern insulators and the W^{∞} algebra, Phys. Rev. B **85**, 241308(R) (2012).
- [43] A. Abouelkomsan, Z. Liu, and E. J. Bergholtz, Particle-Hole Duality, Emergent Fermi Liquids, and Fractional Chern Insulators in Moiré Flatbands, Phys. Rev. Lett. **124**, 106803 (2020).
- [44] C. Repellin and T. Senthil, Chern bands of twisted bilayer graphene: Fractional Chern insulators and spin phase transition, Phys. Rev. Res. 2, 023238 (2020).
- [45] B. Andrews and A. Soluyanov, Fractional quantum Hall states for moiré superstructures in the Hofstadter regime, Phys. Rev. B 101, 235312 (2020).
- [46] T. S. Jackson, G. Möller, and R. Roy, Geometric stability of topological lattice phases, Nat. Commun. 6, 8629 (2015).
- [47] J. K. Jain, Composite-Fermion Approach for the Fractional Quantum Hall Effect, Phys. Rev. Lett. 63, 199 (1989).